TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

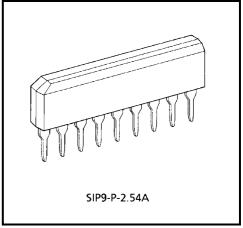
TA8405S

DUAL BRIDGE DRIVER

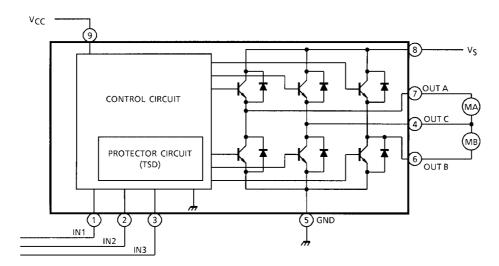
TA8405S is Dual Bridge Driver designed especially for VCR cassette and tape loading motor drives.

FEATURES

- 4 modes available (CW / CCW / STOP / BRAKE)
- Output current up to 0.4 A (AVE.) and 1.0 A (PEAK)
- Wide range of operating voltage: $V_{CC (opr)} = 4.5 \sim 22 \text{ V}$ $V_{S (opr)} = 0 \sim 22 \text{ V}$
- Built-in thermal shutdown, over current protector and Punch-through current restriction circuit.
- Hysteresis for all inputs.



Weight: 0.92 g (Typ.)



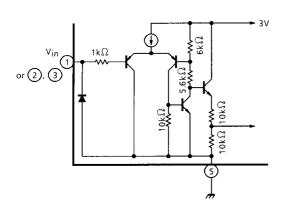
BLOCK DIAGRAM

PIN FUNCTION

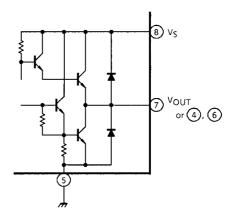
PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION		
1	IN ₁	Input terminal		
2	IN ₂	Input terminal		
3	IN ₃	Input terminal		
4	OUT C	Output terminal		
5	GND	GND terminal		
6	OUT B	Output terminal		
7	OUT A	Output terminal		
8	VS	Supply voltage terminal for motor drive		
9	V _{CC}	Supply voltage terminal for logic		

FUNCTION SPECIFICATION

(1) Input circuit



(2) Output circuit



FUNCTION

INPUT		OUTPUT			MODE			
IN 1	IN 2	IN 3	OUT C	OUT A	OUT B	MA	MB	
0	0	1 / 0	8	8	8	STOP	STOP	
1	0	0	Н	L	8	CW / CCW	STOP	
1	0	1	L	Н	8	CCW / CW	STOP	
0	1	0	Н	8	L	STOP	CW / CCW	
0	1	1	L	8	Н	STOP	CCW / CW	
1	1	1 / 0	L	L	L	BRAKE	BRAKE	

∞: High impedance

Note: Inputs are all low active type.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC}	25	V	
Motor Drive Voltage		VS	25	V	
Output Current	PEAK	I _{O (PEAK)}	1.0 (Note 1)	А	
Output Current	AVE.	I _{O (AVE.)}	0.4	~	
Power Dissipation		PD	0.75 (Note 2)	W	
Operating Temperature		T _{opr}	-30~75	°C	
Storage Temperature		T _{stg}	-55~150	°C	

Note 1: Duty 1 / 10, 100 ms

Note 2: No heat sink

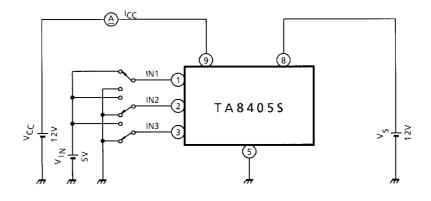
ELECTRICAL CHARACTERISTICS (Unless otherwise specified, Ta = 25°C, V_{CC} = 12 V, V_S = 12 V)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Supply Current		I _{CC1}	1	Output open, CW / CCW mode	-	7	15		
		I _{CC2}	1	Output open, BRAKE mode	-	15	38	mA	
		I _{CC3}	1	Output open, STOP mode	-	7	15		
Input Operating	1 (High)	V _{IN 1}	2	—	3.5	_	5.5	V	
Voltage	2 (Low)	V _{IN 2}	2	—	GND) — 1.2		V	
Input Current		I _{IN}	2	V _{IN} = GND, source mode	-	4	60	μA	
Input Hysteresis Voltage		ΔV_T	2	_	—	1.5	_	V	
Upper		V _{SAT U-1}	3	$I_{O} = 0.4 \text{ A}$, $V_{OUT} - V_{S}$ measure	—	1.0	1.4		
	Lower	VSAT L-1	3	I _O = 0.4 A V _{OUT} -GND measure	_	0.8	1.2	V	
Output Saturation Voltage	Upper	V _{SAT U-2}	3	V _{OUT} –V _S measure I _O = 1.0 A, ON LOAD : 20 ms	_	1.3	2.3		
	Lower	V _{SAT L-2}	3	V _{OUT} -GND measure I _O = 1.0 A, ON LOAD : 20 ms	_	1.0	1.5		
Output Transistor Leakage Current	Upper	Ι _{LU}	5	V _S = 25 V	_	_	50		
	Lower	ارر	5	V _S = 25 V	—	_	50	μA	
Diode Forward Voltage	Upper	V _{FU}	4	I _F = 1.0 A	—	2.1	_	v	
	Lower	V _{FL}	4	I _F = 1.0 A	—	1.6	_		
Thermal Shut Down Operating Temperature		T _{SD}	_	Тј	_	130	_	°C	

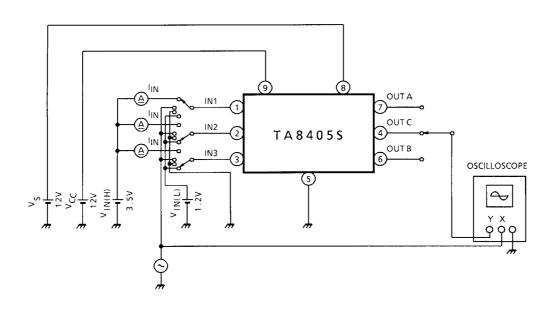
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TEST CIRCUIT 1

ICC1, 2, 3

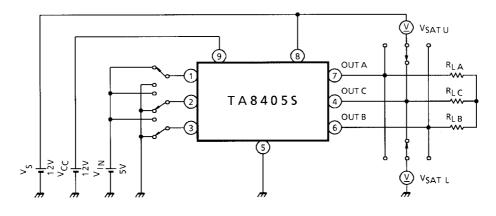


TEST CIRCUIT 2 $V_{IN1, 2}, I_{IN}, \Delta V_T$



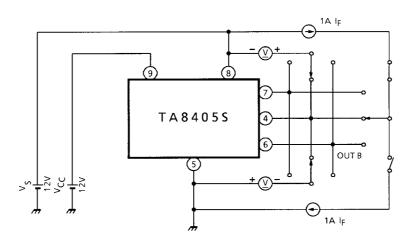
TEST CIRCUIT 3

VSAT U-1, L-1, U-2, L-2

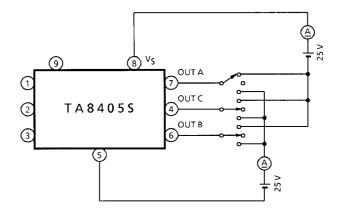


TEST CIRCUIT 4

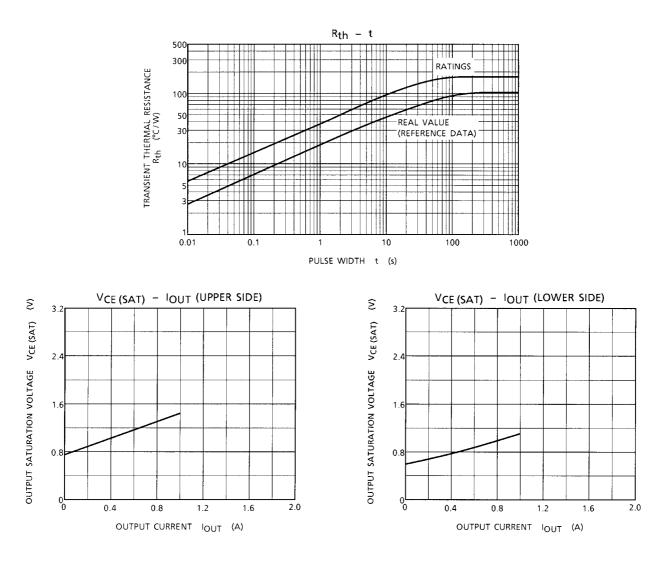
V_{F U, L}



TEST CIRCUIT 5



TOSHIBA

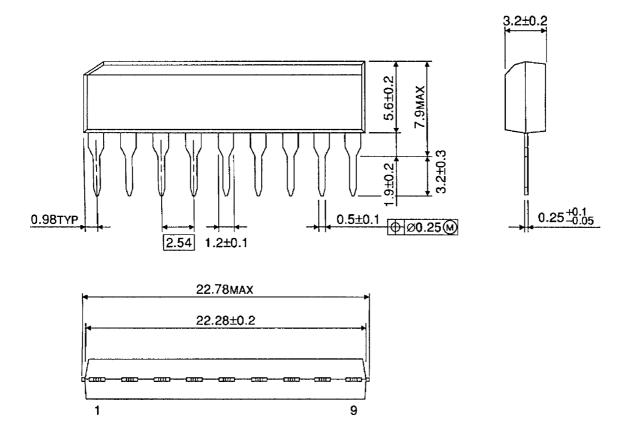


TOSHIBA

PACKAGE DIMENSIONS

SIP9-P-2.54A

Unit: mm



Weight: 0.92 g (Typ.)

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